1 A very low V<sub>F</sub> MEGA Schottky barrier rectifiers

Rev. 02 — 27 March 2007

Pro

Product data sheet

### **Product profile**

### 1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifiers with an integrated guard ring for stress protection, encapsulated in small and flat lead Surface-Mounted Device (SMD) plastic packages.

Table 1. **Product overview** 

| Type number | Package |       | Configuration |  |
|-------------|---------|-------|---------------|--|
|             | NXP     | JEITA |               |  |
| PMEG6010CEH | SOD123F | -     | single        |  |
| PMEG6010CEJ | SOD323F | SC-90 | single        |  |

#### 1.2 Features

Forward current: I<sub>F</sub> ≤ 1 A

Reverse voltage: V<sub>R</sub> ≤ 60 V

Very low forward voltage

Small and flat lead SMD plastic packages

#### 1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Reverse polarity protection
- Low power consumption applications

#### 1.4 Quick reference data

Table 2. **Quick reference data** 

| Symbol  | Parameter       | Conditions                 | Min          | Тур | Max | Unit |
|---------|-----------------|----------------------------|--------------|-----|-----|------|
| $I_{F}$ | forward current | $T_{sp} \le 55  ^{\circ}C$ | -            | -   | 1   | Α    |
| $V_R$   | reverse voltage |                            | -            | -   | 60  | V    |
| $V_{F}$ | forward voltage | I <sub>F</sub> = 1 A       | <u>[1]</u> _ | 570 | 660 | mV   |

[1] Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ .



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## 2. Pinning information

Table 3. Pinning

| Pin | Description | Simplified outline | Symbol                       |
|-----|-------------|--------------------|------------------------------|
| 1   | cathode     | [1]                | . 84                         |
| 2   | anode       | 001aab540          | 1 <del>    2</del><br>sym001 |

<sup>[1]</sup> The marking bar indicates the cathode.

## 3. Ordering information

Table 4. Ordering information

| Type number | Package | ackage                                   |         |  |  |
|-------------|---------|--|---------|--|--|
|             | Name    | Description                              | Version |  |  |
| PMEG6010CEH | -       | plastic surface-mounted package; 2 leads | SOD123F |  |  |
| PMEG6010CEJ | SC-90   | plastic surface-mounted package; 2 leads | SOD323F |  |  |

### 4. Marking

Table 5. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PMEG6010CEH | CA           |
| PMEG6010CEJ | EQ           |

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### 5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter                           | Conditions                                   | Min          | Max  | Unit |
|------------------|-------------------------------------|--|--------------|------|------|
| $V_{R}$          | reverse voltage                     |  | -            | 60   | V    |
| l <sub>F</sub>   | forward current                     | T <sub>sp</sub> ≤ 55 °C                      | -            | 1    | Α    |
| I <sub>FRM</sub> | repetitive peak forward current     | $t_p \leq 1 \text{ ms}; \\ \delta \leq 0.25$ | -            | 7    | Α    |
| I <sub>FSM</sub> | non-repetitive peak forward current | square wave; $t_p = 8 \text{ ms}$            |              |      |      |
|                  | PMEG6010CEH                         |  | -            | 9    | Α    |
|                  | PMEG6010CEJ                         |  | -            | 10   | Α    |
| P <sub>tot</sub> | total power dissipation             | $T_{amb} \le 25  ^{\circ}C$                  |              |      |      |
|                  | PMEG6010CEH                         |  | <u>[1]</u> - | 375  | mW   |
|                  |                                     |  | [2] _        | 830  | mW   |
|                  | PMEG6010CEJ                         |  | <u>[1]</u> - | 350  | mW   |
|                  |                                     |  | [2] _        | 830  | mW   |
| Tj               | junction temperature                |  | -            | 150  | °C   |
| T <sub>amb</sub> | ambient temperature                 |  | -65          | +150 | °C   |
| T <sub>stg</sub> | storage temperature                 |  | -65          | +150 | °C   |
|                  |                                     |  |              |      |      |

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

### 6. Thermal characteristics

Table 7. Thermal characteristics

| Symbol                | Parameter  | Conditions  | Min        | Тур | Max | Unit |
|-----------------------|--|-------------|------------|-----|-----|------|
| $R_{th(j-a)}$         | thermal resistance from junction to ambient      | in free air | <u>[1]</u> |     |     |      |
|                       | PMEG6010CEH                                      |             | [2] _      | -   | 330 | K/W  |
|                       |  |             | [3] _      | -   | 150 | K/W  |
|                       | PMEG6010CEJ                                      |             | [2] _      | -   | 350 | K/W  |
|                       |  |             | [3] _      | -   | 150 | K/W  |
| R <sub>th(j-sp)</sub> | thermal resistance from junction to solder point |             | [4]        |     |     |      |
|                       | PMEG6010CEH                                      |             | -          | -   | 60  | K/W  |
|                       | PMEG6010CEJ                                      |             | -          | -   | 55  | K/W  |

<sup>[1]</sup> For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P<sub>R</sub> are a significant part of the total power losses.

<sup>[2]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

<sup>[2]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

<sup>[3]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

<sup>[4]</sup> Soldering point of cathode tab.

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### 7. Characteristics

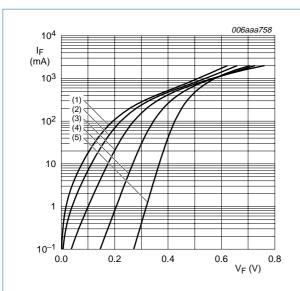
Table 8. Characteristics

 $T_{amb}$  = 25 °C unless otherwise specified.

| · anno — · |                   | and a second a second and a second a second and a second a second and a second and a second and a second and |            |     |     |      |
|------------|-------------------|---|------------|-----|-----|------|
| Symbol     | Parameter         | Conditions  | Min        | Тур | Max | Unit |
| $V_{F}$    | forward voltage   |   | <u>[1]</u> |     |     |      |
|            |                   | I <sub>F</sub> = 1 mA   | -          | 210 | 250 | mV   |
|            |                   | I <sub>F</sub> = 10 mA  | -          | 270 | 310 | mV   |
|            |                   | I <sub>F</sub> = 100 mA   | -          | 350 | 400 | mV   |
|            |                   | I <sub>F</sub> = 500 mA   | -          | 460 | 530 | mV   |
|            |                   | I <sub>F</sub> = 700 mA   | -          | 510 | 580 | mV   |
|            |                   | I <sub>F</sub> = 1 A  | -          | 570 | 660 | mV   |
| $I_R$      | reverse current   | $V_R = 5 V$   | -          | 0.8 | -   | μΑ   |
|            |                   | V <sub>R</sub> = 10 V   | -          | 1.1 | -   | μΑ   |
|            |                   | V <sub>R</sub> = 60 V   | -          | 11  | 50  | μΑ   |
| $C_d$      | diode capacitance | $V_R = 1 V$ ; $f = 1 MHz$   | -          | 60  | 68  | pF   |
|            |                   |   |            |     |     |      |

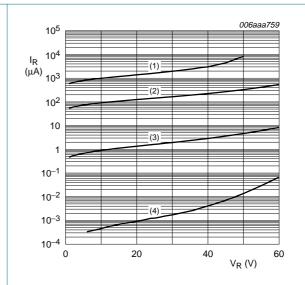
<sup>[1]</sup> Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

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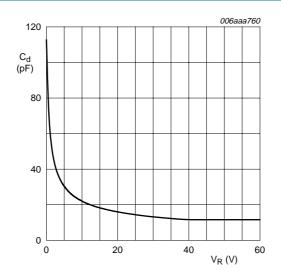
- (1)  $T_{amb} = 150 \, ^{\circ}C$
- (2)  $T_{amb} = 125 \, ^{\circ}C$
- (3)  $T_{amb} = 85 \, ^{\circ}C$
- (4)  $T_{amb} = 25 \, ^{\circ}C$
- (5)  $T_{amb} = -40 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$
- (4)  $T_{amb} = -40 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values

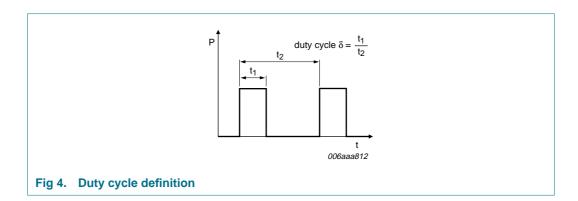


 $f = 1 \text{ MHz}; T_{amb} = 25 \,^{\circ}\text{C}$ 

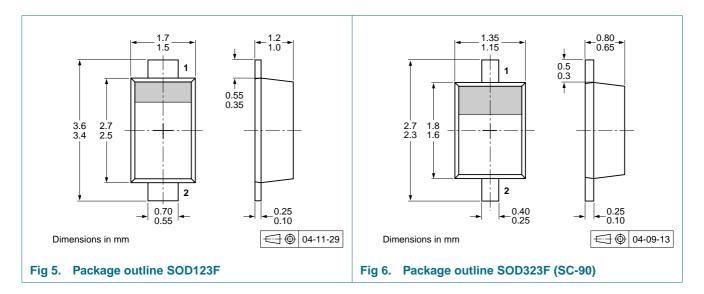
Fig 3. Diode capacitance as a function of reverse voltage; typical values

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### 8. Test information



## 9. Package outline



## 10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

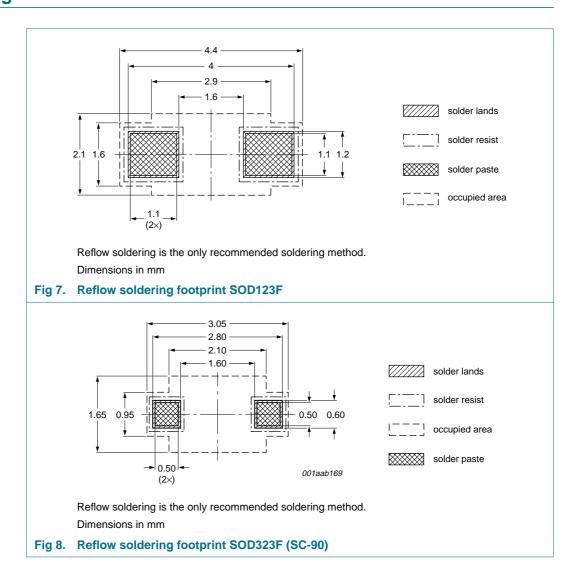
| Type number | Package | Description                    | Packing of | <b>μ</b> uantity |
|-------------|---------|--------------------------------|------------|------------------|
|             |         |                                | 3000       | 10000            |
| PMEG6010CEH | SOD123F | 4 mm pitch, 8 mm tape and reel | -115       | -135             |
| PMEG6010CEJ | SOD323F | _                              |            |                  |

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[1] For further information and the availability of packing methods, see Section 14.

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## 11. Soldering



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## 12. Revision history

### Table 10. Revision history

| Document ID                   | Release date  | Data sheet status           | Change notice      | Supersedes        |  |
|-------------------------------|---|-----------------------------|--------------------|-------------------|--|
| PMEG6010CEH_PMEG6010CEJ_<br>2 | 20070327  | Product data sheet          | -                  | PMEG6010CEJ_1     |  |
| Modifications:                | <ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul> |                             |                    |                   |  |
|                               | 3   | •                           | new company name w | here appropriate. |  |
|                               | <ul> <li>Type number</li> </ul>   | er PMEG6010CEH added        |                    |                   |  |
|                               | • Section 1.1   | "General description": amo  | ended              |                   |  |
|                               | <ul> <li>Table 1 "Pro</li> </ul>  | duct overview": added       |                    |                   |  |
|                               | • Table 7 "The  | ermal characteristics": Tab | e note 1 amended   |                   |  |
|                               | <ul> <li>Section 8 "T</li> </ul>  | est information": added     |                    |                   |  |
| PMEG6010CEJ_1                 | 20060414  | Product data sheet          | -                  | -                 |  |

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#### 13.1 Data sheet status

| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification     | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production        | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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### **NXP Semiconductors**

# PMEG6010CEH; PMEG6010CEJ

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